

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

MCH3477 — General-Purpose Switching Device **Applications**

Features

- · Ultrahigh-speed switching.
- 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		4.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	18	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			I I = i4
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.0	3.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =2A, V _{GS} =4.5V		29	38	mΩ
	R _{DS} (on)2	I _D =1A, V _G S=2.5V		43	61	mΩ
	RDS(on)3	ID=0.5A, VGS=1.8V		69	99	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		410		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		84		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		59		pF

Marking: FJ Continued on next page.

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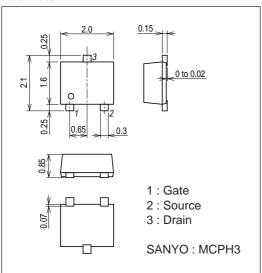
MCH3477

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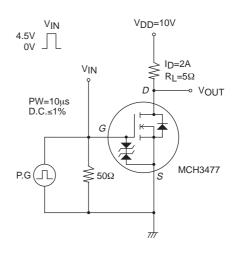
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Uill
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		7.5		ns
Rise Time	t _r	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		38		ns
Fall Time	tf	See specified Test Circuit.		32		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		5.1		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		0.7		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		1.7		nC
Diode Forward Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.78	1.2	V

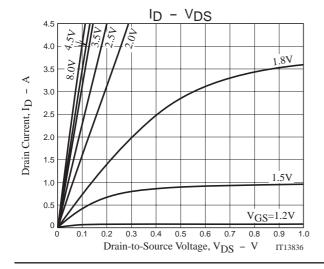
Package Dimensions

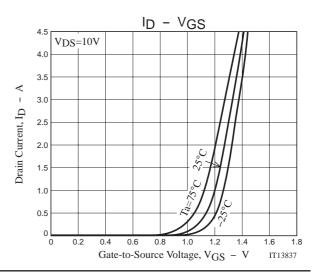
unit : mm (typ) 7019A-003

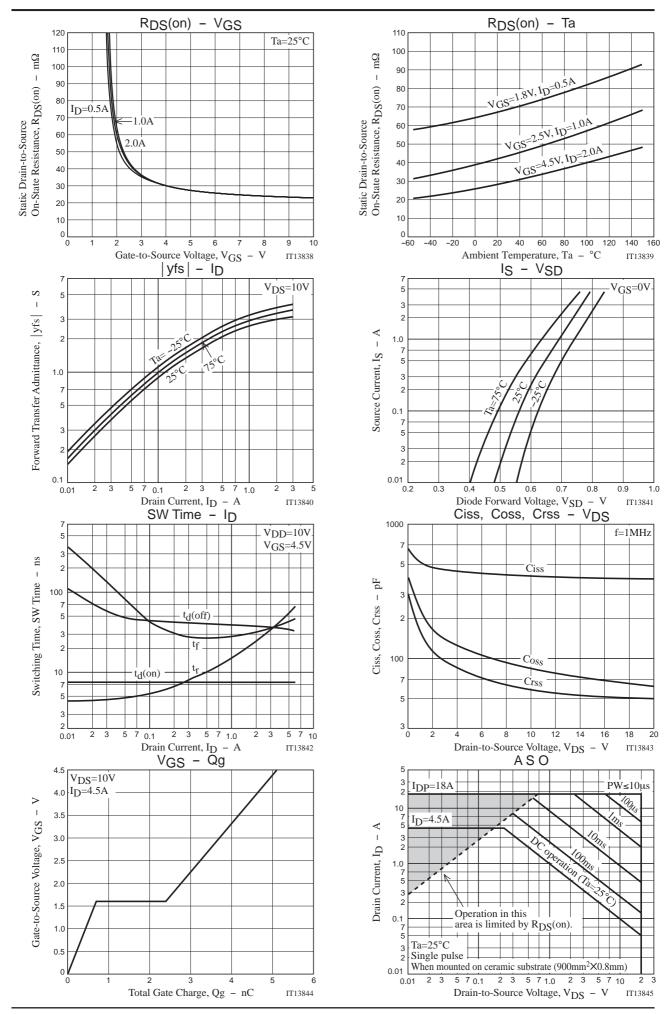


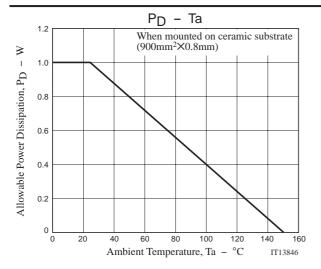
Switching Time Test Circuit











Note on usage: Since the MCH3477 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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